() IDT.

LOW-VOLTAGE 10-BIT BUS SWITCH WITH PRECHARGED OUTPUTS

IDT74CBTLV6800

FEATURES:

- Functionally equivalent to QS3800
- 5Ω A/B bi-directional switch
- · Isolation under power-off conditions
- · Over-voltage tolerant
- · Latch-up performance exceeds 100mA
- Vcc = 2.3V 3.6V, Normal Range
- ESD > 2000V per MIL-STD-883, Method 3015;
 > 200V using machine model (C = 200pF, R = 0)
- Available in QSOP and TSSOP packages

APPLICATIONS:

• 3.3V High Speed Bus Switching and Bus Isolation

FUNCTIONAL BLOCK DIAGRAM

DESCRIPTION:

The CBTLV6800 provides 10-bits of high-speed bus switching with low on-state resistance of the switch allowing connections to be made with minimal propagation delay. The device also precharges the B port to a user-selectable bias voltage (BIASV) to minimize live-insertion noise.

The CBTLV6800 is organized as a single 10-bit bus switch with a single output-enable (\overline{OE}) input. When \overline{OE} is low, the 10-bit bus switch is on and port A is connected to port B. When \overline{OE} is high, the switch is open, and a high impedance state exists between the two ports, and port B is precharged to BIASV through the equivalent of a 10-k Ω resistor.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to Vcc through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

SIMPLIFIED SCHEMATIC, EACH SWITCH





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DECEMBER 2014

IDT74CBTLV6800 LOW-VOLTAGE 10-BIT BUS SWITCH WITH PRECHARGED OUTPUTS

INDUSTRIAL TEMPERATURE RANGE

PIN CONFIGURATION



QSOP / TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max U	
Vcc	SupplyVoltage Range	–0.5 to +4.6 V	
VI	Input Voltage Range	–0.5 to +4.6	V
	Continuous Channel Current	128	mA
Ік	Input Clamp Current, VI/O < 0	-50	mA
Tstg	Storage Temperature	–65 to +150	°C

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

FUNCTION TABLE(1)

Input OE	Inputs/Outputs
L	A Port = B Port
Н	A Port = Z B Port = BIASV

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

Z = High-Impedance

OPERATING CHARACTERISTICS, $TA = 25^{\circ}C^{(1)}$

Symbol	Parameter Test Conditions		Min.	Max.	Unit
Vcc	Supply Voltage	2.3	3.6	V	
BIASV	Bias Voltage		1.3	Vcc	V
Vih	High-Level Control Input Voltage	Vcc = 2.3V to 2.7V	1.7	—	V
		Vcc = 2.7V to 3.6V	2	—	
Vil	Low-Level Control Input Voltage	Vcc = 2.3V to 2.7V	—	0.7	V
		Vcc = 2.7V to 3.6V	_	0.8	
TA	Operating Free-Air Temperature		-40	85	°C

NOTE:

1. All unused control inputs of the device must be held at Vcc or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Operating Conditions: TA = -40 °C to +85 °C

Symbol	Parameter	Test Condit	ions	Min.	Тур.	Max.	Unit
Vik	Control Inputs, Data Inputs	Vcc = 3V, II = -18mA			_	-1.2	V
li	Control Inputs	Vcc = 3.6V, VI = Vcc or GND		—	—	±1	μA
loz	Data I/O	Vcc = 3.6V, Vo = 0 or 3.6V, switch	disabled	—	_	±20	μA
loff		Vcc = 0, Vi or Vo = 0 to 3.6V		_	—	50	μA
lo		Vcc = 3V, BIASV = 2.4V, Vo = 0	, OE = Vcc	0.25	—		mA
lcc		Vcc = 3.6V, Io = 0, VI = Vcc or GND		—	_	10	μA
$\Delta ICC^{(1)}$	Control Inputs	Vcc = 3.6V, one input at 3V, other inputs at Vcc or GND		—	—	300	μA
Сі	Control Inputs	Vi = 3V or 0		—	4	—	pF
CIO(OFF)		Vo = 3V or 0, switch OFF, BIASV = Open, \overline{OE} = Vcc		—	7	—	pF
	Vcc = 2.3V	VI = 0	lı = 64mA	_	5	8	
	Typ. at Vcc = 2.5V		lı = 24mA	_	5	8	
Ron ⁽²⁾		VI = 1.7V	lı = 15mA		27	40	Ω
		VI = 0	lı = 64mA	_	5	7	
	Vcc = 3V		lı = 24mA	—	5	7	
		VI = 2.4V	lı = 15mA	—	10	15	

NOTES:

1. The increase in supply current is attributable to each current that is at the specified voltage level rather than Vcc or GND.

2. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

SWITCHING CHARACTERISTICS

		$Vcc = 2.5V \pm 0.2V$		Vcc = 3.3V ± 0.3V		
Symbol	Parameter	Min.	Мах.	Min.	Max.	Unit
t PD ⁽¹⁾	Propagation Delay	-	0.15	-	0.25	ns
	A to B or B to A					
tрzн	BIASV = 3V or GND	1	4.8	1	4.5	ns
tezl	OE to A or B					
tрнz	BIASV = 3V or GND	1	5.6	1	5.5	ns
tPLZ	OE to A or B					

NOTE:

1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance driven by an ideal voltage source (zero output impedance).

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INDUSTRIAL TEMPERATURE RANGE

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	Vcc ⁽²⁾ =2.5V±0.2V	Unit
VLOAD	6	2 x Vcc	V
Vih	3	Vcc	V
Vт	1.5	Vcc / 2	V
Vlz	300	150	mV
VHZ	300	150	mV
CL	50	30	pF



Test Circuits for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns.

2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2.5ns.

SWITCH POSITION

Test	Switch
tPLZ/tPZL	Vload
tpнz/tpzн	GND
ted	Open







Enable and Disable Times

ORDERING INFORMATION



Datasheet Document History

12/18/2014 Pg. 5

Updated the ordering information by removing the "IDT" notation, non RoHS part and by adding Tape and Reel information.



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